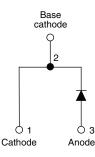
VS-HFA08PB60-N3

Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 8 A



www.vishay.com



| PRIMARY CHARACTERISTICS | | | | | |
|----------------------------------|-------------|--|--|--|--|
| I _{F(AV)} | 8 A | | | | |
| V _R | 600 V | | | | |
| V _F at I _F | 1.4 V | | | | |
| t _{rr} typ. | 18 ns | | | | |
| T _J max. | 150 °C | | | | |
| Package | TO-247AC 2L | | | | |
| Circuit configuration | Single | | | | |

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

VS-HFA08PB60... is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 8 A continuous current, the VS-HFA08PB60... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA08PB60... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--|-----------------------------------|-------------------------|-------------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Cathode to anode voltage | V _R | | 600 | V | | |
| Maximum continuous forward current | ١ _F | T _C = 100 °C | 8 | | | |
| Single pulse forward current | I _{FSM} | t _p = 10 ms | 60 | А | | |
| Maximum repetitive forward current | I _{FRM} | | 24 | | | |
| Maximum nawar discipation | P _D | T _C = 25 °C | 36 | 14/ | | |
| Maximum power dissipation | | T _C = 100 °C | 14 | W | | |
| Operating junction and storage temperature range | T _J , T _{Stg} | | -55 to +150 | °C | | |

RoHS COMPLIANT HALOGEN FREE

Revision: 29-Nov-2019

Document Number: 94041

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VS-HFA08PB60-N3



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| ELECTRICAL SPECIFICATIONS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified) | | | | | | | |
|---|------------------------|---|------------|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| Cathode to anode breakdown voltage | V _{BR} | I _R = 100 μA | | 600 | - | - | |
| | | I _F = 8.0 A | | - | 1.4 | 1.7 | v |
| Maximum forward voltage | oltage V _{FM} | I _F = 16 A | See fig. 1 | - | 1.7 | 2.1 | |
| | | $I_F = 8.0 \text{ A}, T_J = 125 \text{ °C}$ | | - | 1.4 | 1.7 | |
| Maximum reverse | | $V_{R} = V_{R}$ rated | 0 | - | 0.3 | 5.0 | μA |
| leakage current | I _{RM} | T_J = 125 °C, V_R = 0.8 x V_R rated | See fig. 2 | - | 100 | 500 | |
| Junction capacitance | CT | V _R = 200 V See fig. 3 | | - | 10 | 25 | pF |
| Series inductance | L _S | Measured lead to lead 5 mm from package body - 8.0 - nH | | | nH | | |

| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified) | | | | | | | |
|---|---------------------------|---|--|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | MIN. | TYP. | MAX. | UNITS |
| | t _{rr} | I _F = 1.0 A, dI _F /dt = 200 A/μs, V _R = 30 V | | - | 18 | - | |
| Reverse recovery time See fig. 5, 10 | t _{rr1} | T _J = 25 °C | | - | 37 | 55 | ns |
| 000 lig. 0, 10 | t _{rr2} | T _J = 125 °C | | - | 55 | 90 | |
| Peak recovery current | I _{RRM1} | T _J = 25 °C | I _F = 8.0 A dI _F /dt = 200 A/µs V _R = 200 V | - | 3.5 | 5.0 | А |
| See fig. 6 | I _{RRM2} | T _J = 125 °C | | - | 4.5 | 8.0 | A |
| Reverse recovery charge | Q _{rr1} | T _J = 25 °C | | - | 65 | 138 | nC |
| See fig. 7 | Q _{rr2} | T _J = 125 °C | | - | 124 | 360 | ne |
| Peak rate of fall of recovery | dl _{(rec)M} /dt1 | T _J = 25 °C | | - | 240 | - | A /uo |
| current during t _b See fig. 8 | dl _{(rec)M} /dt2 | T _J = 125 °C | | - | 210 | - | A/µs |

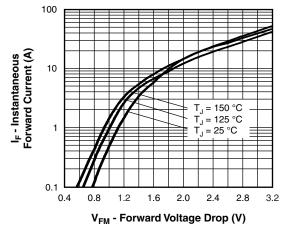
| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|--|-------------------|---|--------------|------|------------|------------------------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Lead temperature | T _{lead} | 0.063" from case (1.6 mm) for 10 s | - | - | 300 | °C | |
| Thermal resistance, junction to case | R _{θJC} | | - | - | 3.5 | | |
| Thermal resistance, junction to ambient | R _{θJA} | Typical socket mount | - | - | 40 | K/W | |
| Thermal resistance, case to heatsink | $R_{\theta CS}$ | Mounting surface, flat, smooth, and greased | - | 0.25 | - | | |
| Weight | | | - | 6.0 | - | g | |
| Weight | | | - | 0.21 | - | oz. | |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) | |
| Marking device | | Case style TO-247AC 2L | HFA08PB60 | | | | |

Revision: 29-Nov-2019

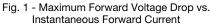
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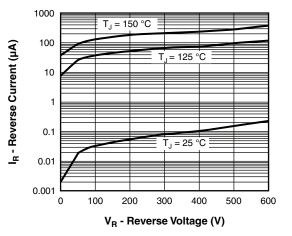


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

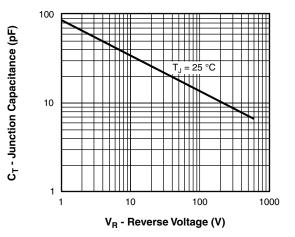


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

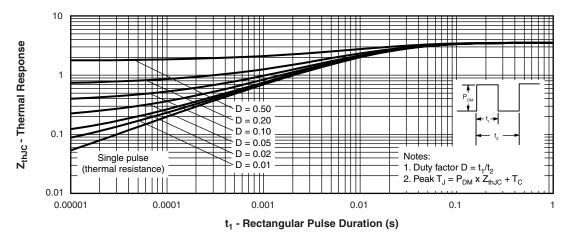


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



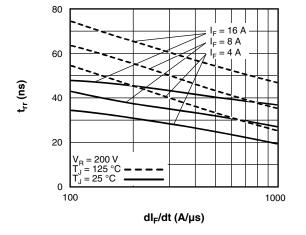


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt (Per Leg)

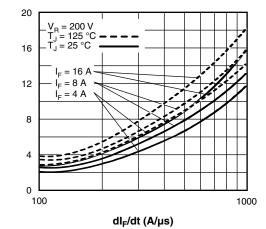


Fig. 6 - Typical Recovery Current vs. dl_F/dt (Per Leg)

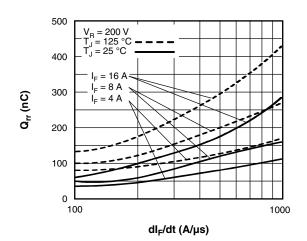


Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Leg)

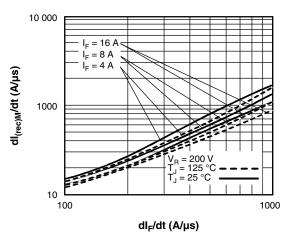


Fig. 8 - Typical dI_{(rec)M}/dt vs. dI_F/dt (Per Leg)

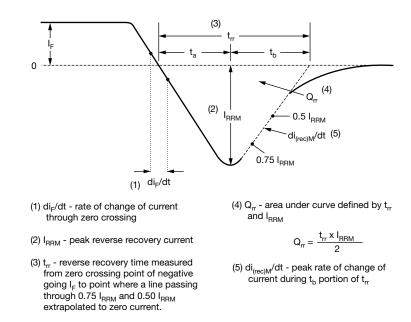


Fig. 9 - Reverse Recovery Waveform and Definitions

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|---|---|--|
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| | E WITHOUT NOTICE. THE PRODUCTS DESCI | |

VS-HFA08PB60-N3

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ORDERING INFORMATION TABLE

| Device code | VS- | HF | Α | 08 | РВ | 60 | -N3 |
|-------------|---------------------------------|---------------------------------|--|------------------------|---------------|----|----------|
| | | 2 | 3 | 4 | 5 | 6 | 7 |
| | 1 · 2 · 3 · 4 · 5 · | · HE · Elec · Cur · PB | KFRED [®] ctron irra rent rati = TO-24 | | = 8A) pins | | |
| | 7 - | Env | ironmer | ntal digit en-free, | : | | int, and |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-HFA08PB60-N3 | 25 | 500 | Antistatic plastic tube | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|---|--|--|--|--|--|
| Dimensions www.vishay.com/doc?96144 | | | | | |
| Part marking information www.vishay.com/doc?95648 | | | | | |



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